

### Vishay Semiconductors

# **Small Signal Schottky Diode**



### **DESIGN SUPPORT TOOLS** click logo to get started



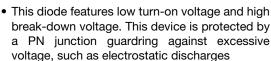
#### **MECHANICAL DATA**

Case: MiniMELF (SOD-80)
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

#### **FEATURES**







RoHS

- This diode is also available in the DO-35 (DO-204AH) case with type designation BAT46 and in the SOD-123 case with type designation BAT46W-V
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

| PARTS TABLE |                        |                       |              |               |  |
|-------------|------------------------|-----------------------|--------------|---------------|--|
| PART        | ORDERING CODE          | CIRCUIT CONFIGURATION | TYPE MARKING | REMARKS       |  |
| LL46        | LL46-GS18 or LL46-GS08 | Single                | -            | Tape and reel |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                    |                  |       |      |  |
|--|------------------------------------|------------------|-------|------|--|
| PARAMETER  | TEST CONDITION                     | SYMBOL           | VALUE | UNIT |  |
| Repetitive peak reverse voltage  |                                    | V <sub>RRM</sub> | 100   | V    |  |
| Forward continuous current (1)   |                                    | I <sub>F</sub>   | 150   | mA   |  |
| Repetitive peak forward current (1)  | $t_p < 1 \text{ s, } \delta < 0.5$ | I <sub>FRM</sub> | 350   | mA   |  |
| Surge forward current (1)  | t <sub>p</sub> = 10 ms             | I <sub>FSM</sub> | 750   | mA   |  |
| Power dissipation (1)  | T <sub>amb</sub> = 80 °C           | P <sub>tot</sub> | 200   | mW   |  |

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                  |             |      |  |  |
|--|----------------|------------------|-------------|------|--|--|
| PARAMETER  | TEST CONDITION | SYMBOL           | VALUE       | UNIT |  |  |
| Thermal resistance junction to ambient air (1)                                 |                | $R_{thJA}$       | 300         | K/W  |  |  |
| Junction temperature   |                | Tj               | 125         | °C   |  |  |
| Ambient operating temperature range  |                | T <sub>amb</sub> | -55 to +125 | °C   |  |  |
| Storage temperature range  |                | T <sub>stg</sub> | -65 to +150 | °C   |  |  |

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |      |      |      |      |
|--|--|-------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION                                   | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Reverse breakdown voltage  | I <sub>R</sub> = 100 μA (pulsed)                 | V <sub>(BR)</sub> | 100  |      |      | V    |
|  | V <sub>R</sub> = 1.5 V                           | I <sub>R</sub>    |      |      | 0.5  | μΑ   |
|  | $V_R = 1.5 \text{ V}, T_j = 60 ^{\circ}\text{C}$ | I <sub>R</sub>    |      |      | 5    | μΑ   |
|  | $V_R = 10 \text{ V}$                             | I <sub>R</sub>    |      |      | 0.8  | μΑ   |
| Leakage current (1)  | $V_R = 10 \text{ V}, T_j = 60 ^{\circ}\text{C}$  | I <sub>R</sub>    |      |      | 7.5  | μΑ   |
| Leakage Current (*)  | V <sub>R</sub> = 50 V                            | I <sub>R</sub>    |      |      | 2    | μΑ   |
|  | $V_R = 50 \text{ V}, T_j = 60 ^{\circ}\text{C}$  | I <sub>R</sub>    |      |      | 15   | μΑ   |
|  | V <sub>R</sub> = 75 V                            | I <sub>R</sub>    |      |      | 5    | μΑ   |
|  | V <sub>R</sub> = 75 V, T <sub>j</sub> = 60 °C    | I <sub>R</sub>    |      |      | 20   | μA   |
|  | $I_F = 0.1 \text{ mA}$                           | V <sub>F</sub>    |      |      | 250  | mV   |
| Forward voltage (1)  | I <sub>F</sub> = 10 mA                           | V <sub>F</sub>    |      |      | 450  | mV   |
|  | I <sub>F</sub> = 250 mA                          | V <sub>F</sub>    |      |      | 1000 | mV   |
| Diada canacitanas  | V <sub>R</sub> = 0 V, f = 1 MHz                  | C <sub>D</sub>    |      | 10   |      | рF   |
| Diode capacitance  | V <sub>R</sub> = 1 V, f = 1 MHz                  | C <sub>D</sub>    |      | 6    |      | рF   |

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

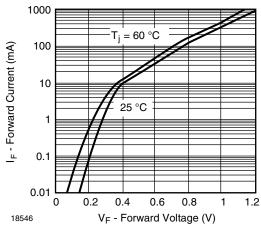


Fig. 1 - Typical Instantaneous Forward Characteristics

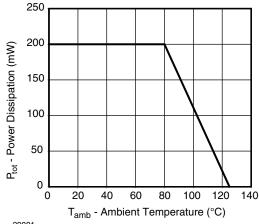


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

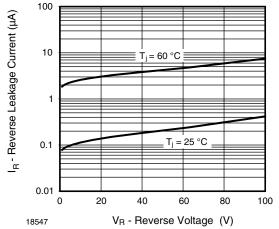
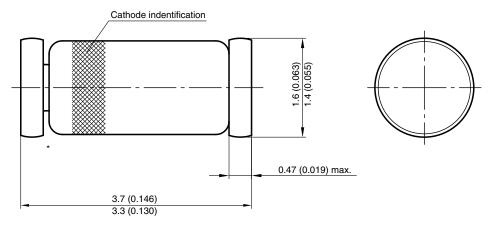


Fig. 2 - Typical Reverse Characteristics

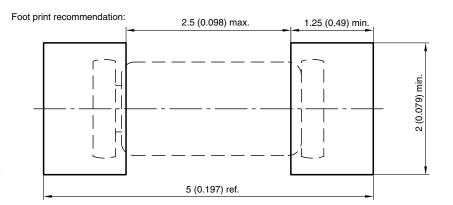
 $<sup>^{(1)}\,</sup>$  Pulse test  $t_p < 300~\mu s,~\delta < 2~\%$ 

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### PACKAGE DIMENSIONS in millimeters (inches): MiniMELF (SOD-80)



\* The gap between plug and glass can be either on cathode or anode side



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